

# N-Channel MOSFET Transistor

## **BF966S**

UHF Transistor

20V / 10mA

# DATASHEET

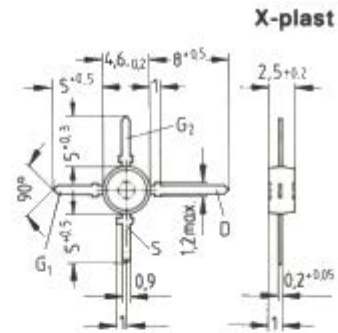
OEM – Siemens

Source: Siemens Databook 1986/87

## Silizium-N-Kanal-MOSFET-Tetrode

BF 966 S

- Für Vorstufen in UHF-TV-Tunern
- Hohe Steilheit
- Kleine Rauschzahl



Typ	BF 966 S
Best.-Nr.	Q62702-F438

## Grenzdaten

Drain-Source-Spannung	$V_{DS}$	20	V
Drainstrom	$I_D$	30	mA
Gate 1/Gate 2-Source-Spitzenstrom	$\pm I_{G1/2SM}$	10	mA
Gesamtverlustleistung $T_A \leq 60^\circ\text{C}$	$P_{tot}$	200	mW
Lagertemperatur	$T_{stg}$	-55...+150	$^\circ\text{C}$
Kanaltemperatur	$T_{Ch}$	150	$^\circ\text{C}$

## Wärmewiderstand

Sperrschicht-Umgebung	$R_{th,JA}$	$\leq 450$	K/W
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## BF 966 S

Kenndaten ( $T_A = 25^\circ\text{C}$ )

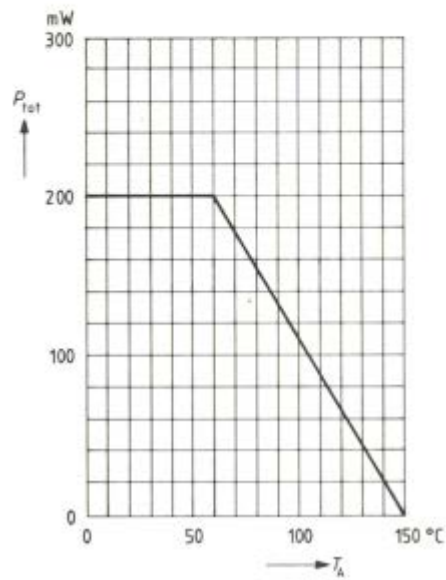
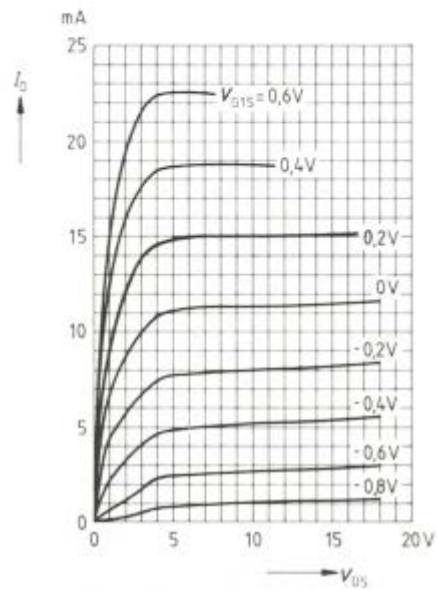
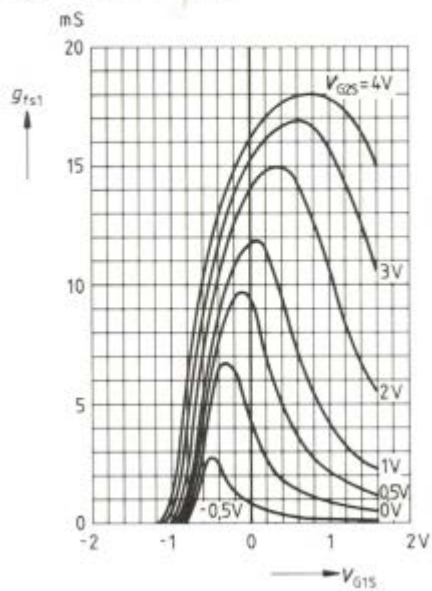
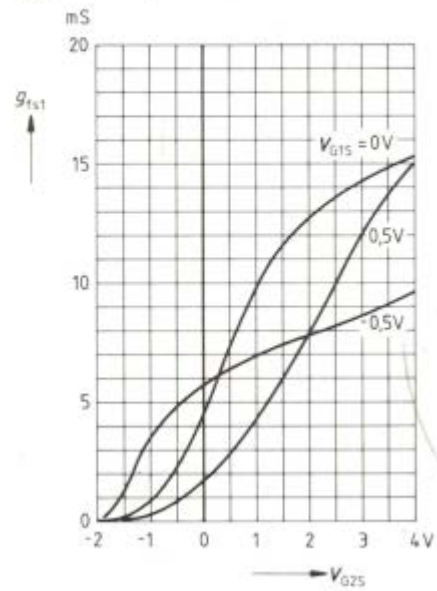
## Gleichstromdaten

		min	typ	max	
Drain-Source-Durchbruchspannung $I_D = 10\ \mu\text{A}$ , $-V_{G1S} = -V_{G2S} = 4\ \text{V}$	$V_{(BR)DS}$	20	—	—	V
Gate 1-Source-Durchbruchspannung $\pm I_{G1S} = 10\ \text{mA}$ , $V_{G2S} = V_{DS} = 0$	$\pm V_{(BR)G1SS}$	8,5	—	17	V
Gate 2-Source-Durchbruchspannung $\pm I_{G2S} = 10\ \text{mA}$ , $V_{G1S} = V_{DS} = 0$	$\pm V_{(BR)G2SS}$	8,5	—	17	V
Gate 1-Reststrom $\pm V_{G1S} = 5\ \text{V}$ , $V_{G2S} = V_{DS} = 0$	$\pm I_{G1SS}$	—	—	50	nA
Gate 2-Reststrom $\pm V_{G2S} = 5\ \text{V}$ , $V_{G1S} = V_{DS} = 0$	$\pm I_{G2SS}$	—	—	50	nA
Drainstrom $V_{DS} = 15\ \text{V}$ , $V_{G1S} = 0$ , $V_{G2S} = 4\ \text{V}$	$I_{DSS}$	2	—	20	mA
Gate 1-Source-Abschnürspannung $V_{DS} = 15\ \text{V}$ , $V_{G2S} = 4\ \text{V}$ , $I_D = 20\ \mu\text{A}$	$-V_{G1S(p)}$	—	—	2,5	V
Gate 2-Source-Abschnürspannung $V_{DS} = 15\ \text{V}$ , $V_{G1S} = 0$ , $I_D = 20\ \mu\text{A}$	$-V_{G2S(p)}$	—	—	2	V

## Wechselstromdaten

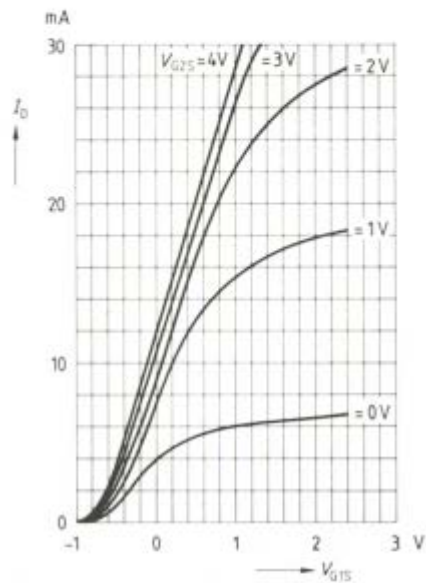
Vorwärtssteilheit $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ , $V_{G2S} = 4\ \text{V}$ , $f = 1\ \text{kHz}$	$g_{fs}$	15	18	—	mS
Gate 1-Eingangskapazität $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ , $V_{G2S} = 4\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{G1SS}$	—	2,3	—	pF
Gate 2-Eingangskapazität $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ , $V_{G2S} = 4\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{G2SS}$	—	1,1	—	pF
Rückwirkungskapazität $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ , $V_{G2S} = 4\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{dg1}$	—	25	—	fF
Ausgangskapazität $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ , $V_{G2S} = 4\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{dss}$	—	0,8	—	pF
Leistungsverstärkung $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ $f = 200\ \text{MHz}$ , $G_G = 2\ \text{mS}$ , $G_L = 0,5\ \text{mS}$ (Meßschaltung 1)	$G_{ps}$	—	25	—	dB
$f = 800\ \text{MHz}$ , $G_G = 3,3\ \text{mS}$ , $G_L = 1\ \text{mS}$ (Meßschaltung 2)		—	18	—	dB
Rauschzahl $V_{DS} = 15\ \text{V}$ , $I_D = 10\ \text{mA}$ $f = 200\ \text{MHz}$ , $G_G = 2\ \text{mS}$ , $G_L = 0,5\ \text{mS}$ (Meßschaltung 1)	$F$	—	1	—	dB
$f = 800\ \text{MHz}$ , $G_G = 3,3\ \text{mS}$ , $G_L = 1\ \text{mS}$ (Meßschaltung 2)		—	1,8	—	dB
Regelumfang $V_{DS} = 15\ \text{V}$ , $V_{G2S} = 4 \dots -2\ \text{V}$ , $f = 800\ \text{MHz}$ (Meßschaltung 2)	$\Delta G_{ps}$	40	—	—	dB

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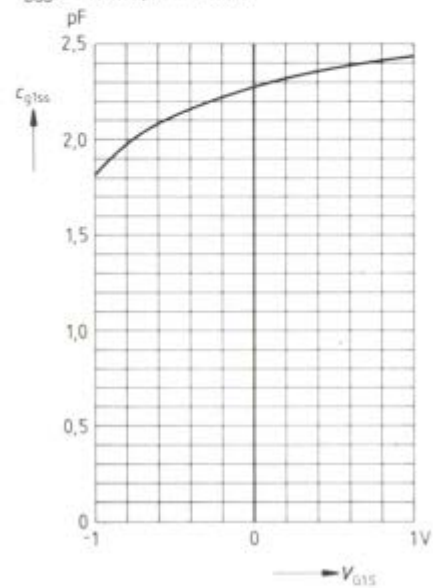
Gesamtverlustleistung  $P_{\text{tot}} = f(T_A)$ Ausgangskennlinienfeld  $I_D = f(V_{\text{DS}})$  $V_{\text{GS}} = 4 \text{ V}$ Gate 1-Steilheit  $g_{fs1} = f(V_{\text{GS1}})$  $V_{\text{DS}} = 15 \text{ V}$  $I_{\text{DSS}} = 10 \text{ mA}, f = 1 \text{ kHz}$ Gate 1-Steilheit  $g_{fs1} = f(V_{\text{GS2}})$  $V_{\text{DS}} = 15 \text{ V}$  $I_{\text{DSS}} = 10 \text{ mA}, f = 1 \text{ kHz}$ 

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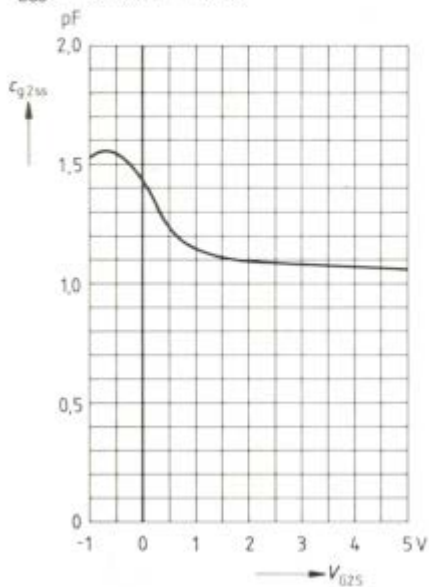
**Drainstrom  $I_D = f(V_{G1S})$**   
 $V_{DS} = 15\text{ V}$



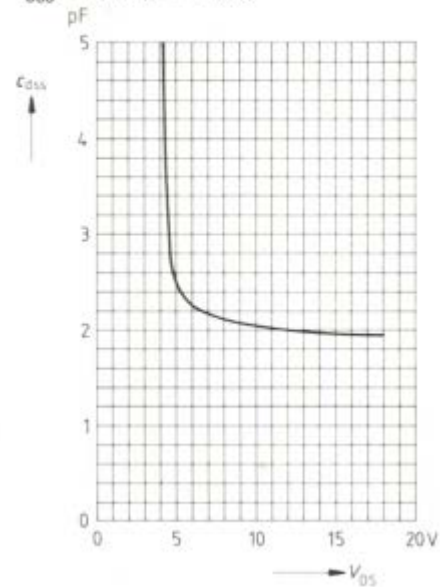
**Gate 1-Eingangskapazität  $c_{g1ss} = f(V_{G1S})$**   
 $V_{G2S} = 4\text{ V}$ ,  $V_{DS} = 15\text{ V}$   
 $I_{DSS} = 10\text{ mA}$ ,  $f = 1\text{ MHz}$



**Gate 2-Eingangskapazität  $c_{g2ss} = f(V_{G2S})$**   
 $V_{G1S} = 0\text{ V}$ ,  $V_{DS} = 15\text{ V}$   
 $I_{DSS} = 10\text{ mA}$ ,  $f = 1\text{ MHz}$

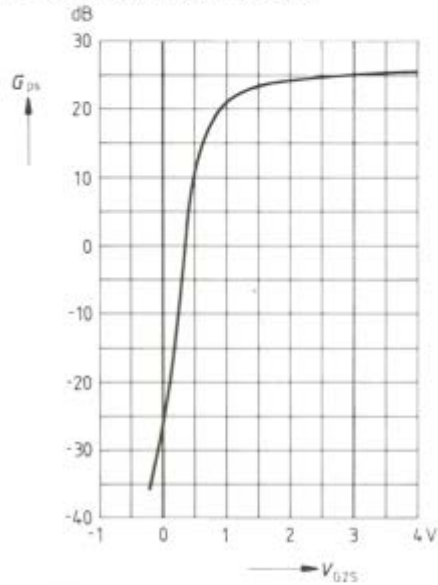


**Ausgangskapazität  $c_{dss} = f(V_{DS})$**   
 $V_{G1S} = 0\text{ V}$ ,  $V_{G2S} = 4\text{ V}$   
 $I_{DSS} = 10\text{ mA}$ ,  $f = 1\text{ MHz}$

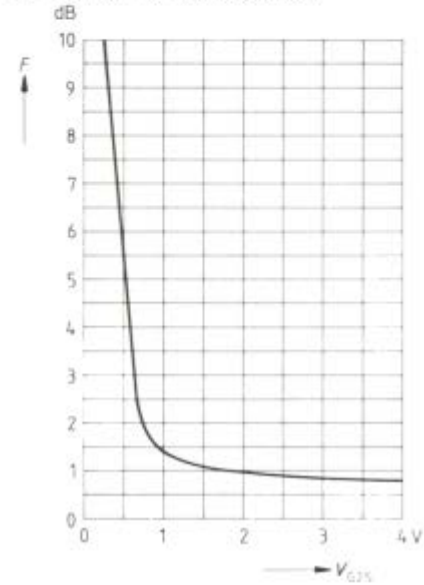


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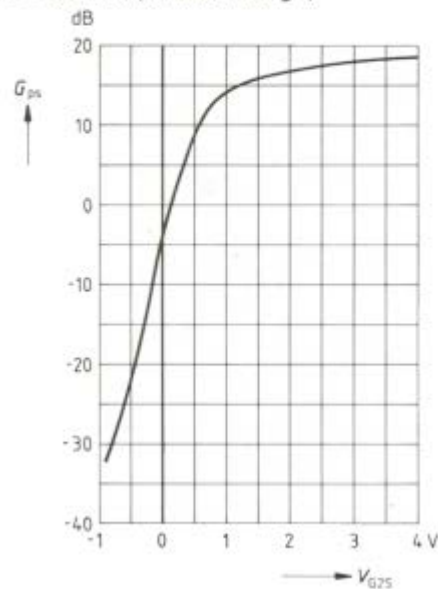
**Leistungsverstärkung  $G_{ps} = f(V_{G2S})$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{G1S} = 0\text{ V}$ ,  $I_{DSS} = 10\text{ mA}$   
 $f = 200\text{ MHz}$  (s. Meßschaltung 1)



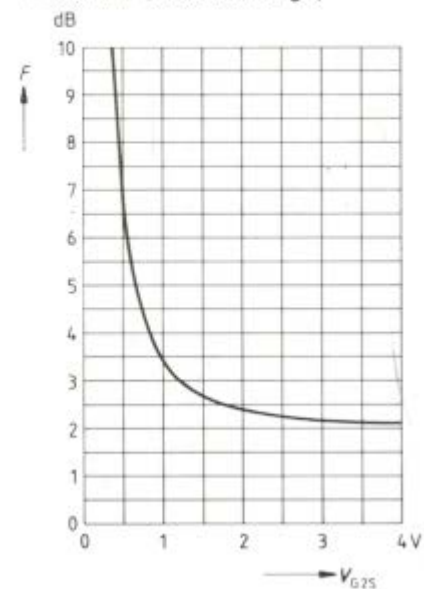
**Rauschzahl  $F = f(V_{G2S})$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{G1S} = 0\text{ V}$ ,  $I_{DSS} = 10\text{ mA}$   
 $f = 200\text{ MHz}$  (s. Meßschaltung 1)



**Leistungsverstärkung  $G_{ps} = f(V_{G2S})$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{G1S} = 0\text{ V}$ ,  $I_{DSS} = 10\text{ mA}$   
 $f = 800\text{ MHz}$  (s. Meßschaltung 2)

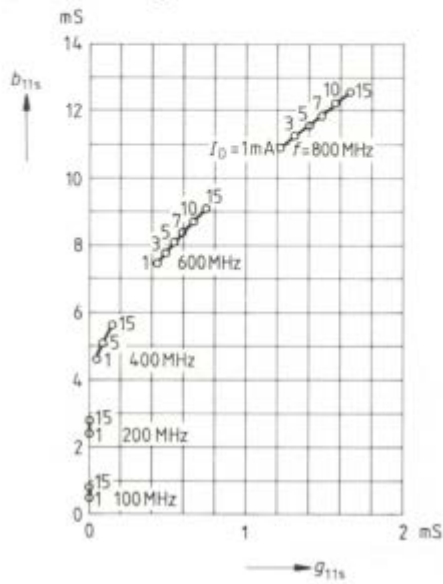


**Rauschzahl  $F = f(V_{G2S})$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{G1S} = 0\text{ V}$ ,  $I_{DSS} = 10\text{ mA}$   
 $f = 800\text{ MHz}$  (s. Meßschaltung 2)

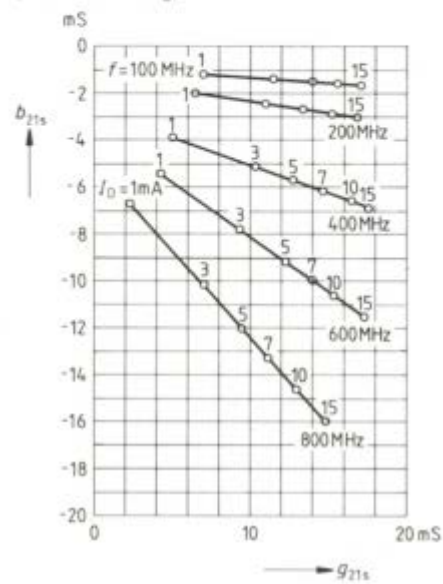


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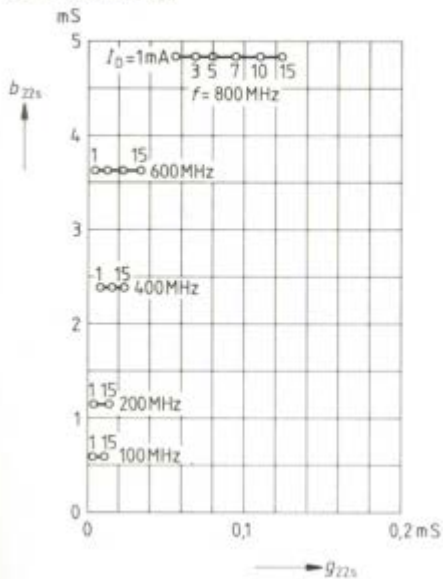
**Gate 1-Eingangsleitwert  $y_{11s}$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{GS} = 4\text{ V}$   
 (Sourceschaltung)



**Gate 1-Steilheit  $y_{21s}$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{GS} = 4\text{ V}$   
 (Sourceschaltung)

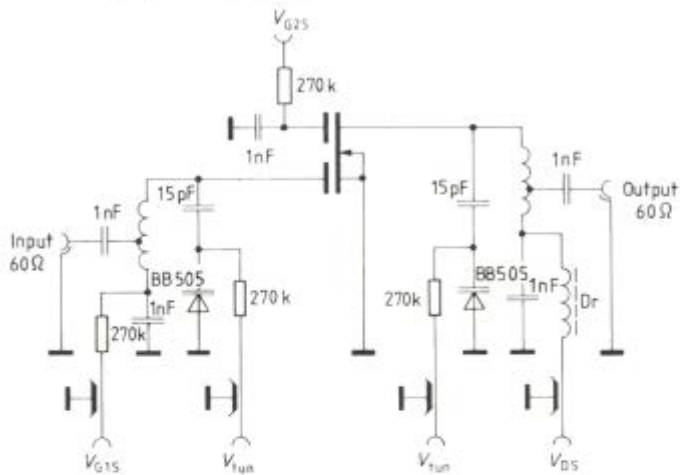


**Ausgangsleitwert  $y_{22s}$**   
 $V_{DS} = 15\text{ V}$ ,  $V_{GS} = 4\text{ V}$   
 (Sourceschaltung)



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**Meßschaltung 1 für Leistungsverstärkung und Rauschen**  
 $f = 200 \text{ MHz}$ ,  $G_G = 2 \text{ mS}$ ,  $G_L = 0.5 \text{ mS}$



**Meßschaltung 2 für Leistungsverstärkung, Rauschen und Kreuzmodulation**  
 $f = 800 \text{ MHz}$ ,  $G_G = 3.3 \text{ mS}$ ,  $G_L = 1.0 \text{ mS}$

